



DMT12H065LFDF

Product Summary

BV _{DSS}	BV _{DSS} @ T _{J Max}	R _{DS(ON)} Max	I _D Max T _A = +25°C
		65mΩ @ V _{GS} = 10V	4.3A
115V 120V	70mΩ @ V _{GS} = 4.5V	4.5A	

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- DC-DC Primary Switch
- Load Switch

115V N-CHANNEL ENHANCEMENT MODE MOSFET

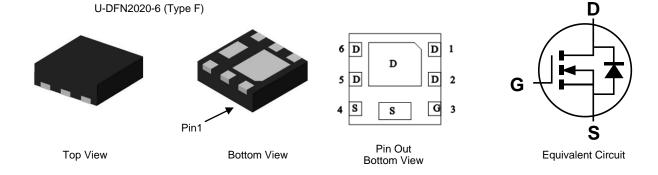
Features and Benefits

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.0065 grams (Approximate)

8



Ordering Information (Note 4)

	Part Number	Case	Quantity Per Reel				
	DMT12H065LFDF-7	U-DFN2020-6 (Type F)	3,000				
DMT12H065LFDF-13		U-DFN2020-6 (Type F)	10,000				
Notes:	s: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS). 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.						

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

See https: Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

			U	-DFN2020-6 (Type F)						
				96 ≥	YM = Y = Ye	Product Type Ma Date Code Mar ear (ex: G = 201 lonth (ex: 9 = Se	king 9)				
Date Code Key											
Year	2019	20	020	2021	2022	2023	2024	2025	20	26	2027
Code	G		H	I	J	К	L	М	N	1	0
Month	Jan	Feb	Mar	Apr	May	Jun Ju	Αυα	Sep	Oct	Nov	Dec

Code

D

0



Marking Information (continued)

U-DFN2020-6 (Type F)



96 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 9 = 2019) W = Week (ex: a = week 27; z represents week 52 and 53)

X = Internal Code (ex: U = Monday)

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027
Code	9	0	1	2	3	4	5	6	7
Week	1-	26	27	-52	5	3			
Code	A	-Z	a	-Z		Z			
							•		
Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat		
Code	Т	U	V	W	Х	Y	Z	1	

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	115	V	
Gate-Source Voltage	V _{GSS}	±12	V	
Continuous Drain Current, V _{GS} = 10V (Note 6)	ID	4.3 3.4	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	25	А
Maximum Body Diode Continuous Current (Note 6)		Is	6	А
Pulsed Body Diode Continuous Current (10µs Pulse, Duty Cycle = 1	1%)	I _{SM}	25	А
Avalanche Current, L = 0.3mH	I _{AS}	4	А	
Avalanche Energy, L = 0.3mH		E _{AS}	2.4	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	D	1.0	W
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.6	vv
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ ext{ heta}JA}$	124	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	D	1.8	W
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.2	vv
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ extsf{ heta}JA}$	69	°C/W	
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	13	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

 Notes:
 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.



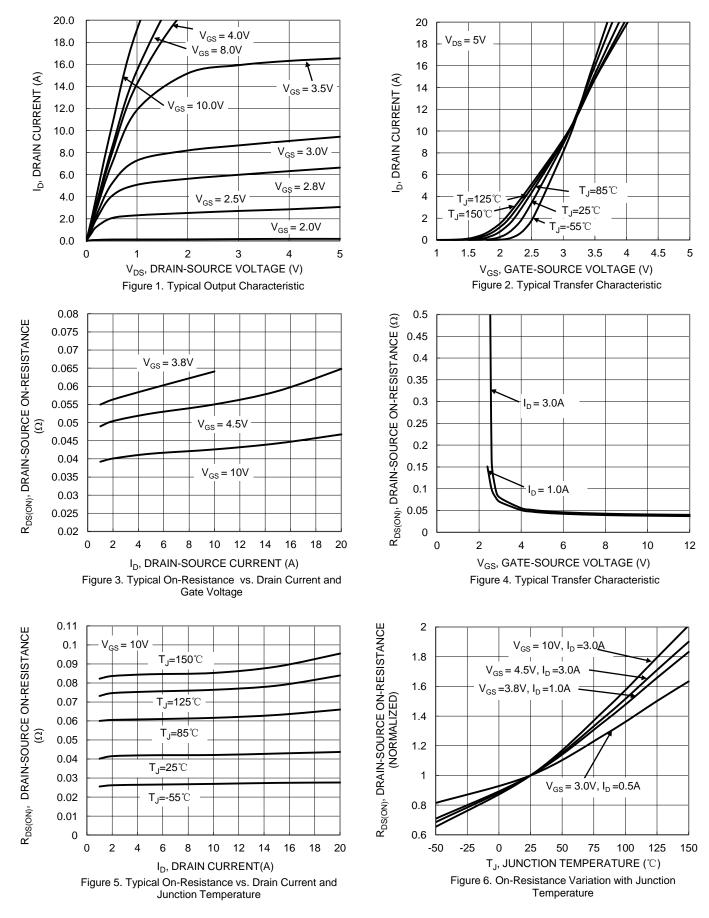
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				•		·
Drain-Source Breakdown Voltage	BV _{DSS}	115	_	—	V	$V_{GS} = 0V, I_{D} = 10mA$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 92V, V_{GS} = 0V$
Gate-Source Leakage	Igss	—	-	±100	nA	$V_{GS} = \pm 9.6V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	•					
Gate Threshold Voltage	V _{GS(TH)}	0.6	_	2.2	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
		_	43	65		$V_{GS} = 10V, I_D = 3A$
Static Drain-Source On-Resistance		_	54	70	mΩ	V _{GS} = 4.5V, I _D = 3A
Static Drain-Source On-Resistance	R _{DS(ON)}		58	150	11122	V _{GS} = 3.8V, I _D = 1.0A
			75	350		$V_{GS} = 3V, I_D = 0.5A$
Diode Forward Voltage	V _{SD}		0.8	1.3	V	$V_{GS} = 0V, I_{S} = 2.4A$
DYNAMIC CHARACTERISTICS (Note 8)						<u> </u>
Input Capacitance	Ciss		252	—	pF	
Output Capacitance	Coss	—	80	—	pF	− V _{DS} = 50V, V _{GS} = 0V, − f = 1MHz
Reverse Transfer Capacitance	Crss		3	—	pF	
Gate Resistance	Rg	—	6.9	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qq		5.5	—	nC	
Gate-Source Charge	Q _{gs}		0.4	—	nC	$V_{DS} = 50V, I_D = 4.5A,$
Gate-Drain Charge	Q _{gd}		1.7	—	nC	$V_{GS} = 10V$
Turn-On Delay Time	t _{D(ON)}	—	2.1	—	ns	
Turn-On Rise Time	t _R		2	_	ns	$V_{DS} = 50V, R_{L} = 11\Omega$
Turn-Off Delay Time	t _{D(OFF)}	—	10	—	ns	$V_{GS} = 10V, R_{GEN} = 3\Omega$
Turn-Off Fall Time	tF	_	3.6	_	ns	1
Reverse Recovery Time	t _{RR}	_	101	_	ns	
Reverse Recovery Charge	Q _{RR}		212	_	nC	I _F = 4.5A, di/dt = 300A/μs

 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing. Notes:



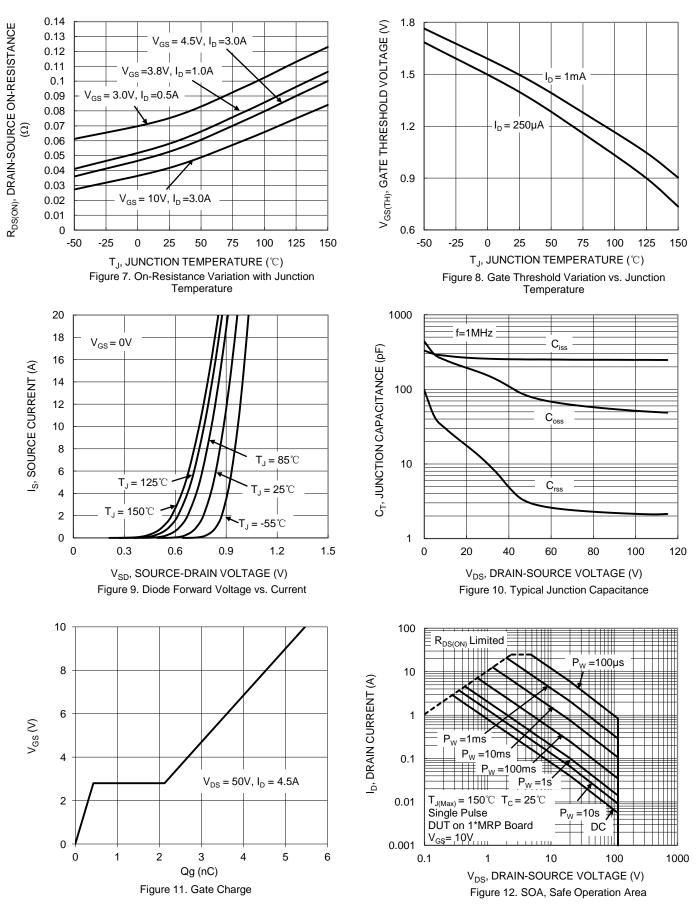
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DMT12H065LFDF Datasheet number: DS40715 Rev. 4 - 2 4 of 8 www.diodes.com July 2019 © Diodes Incorporated

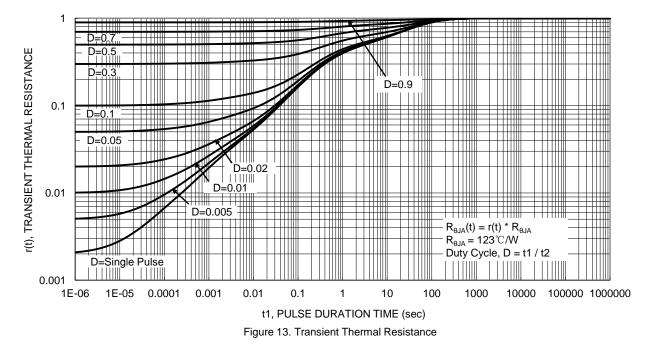


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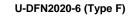


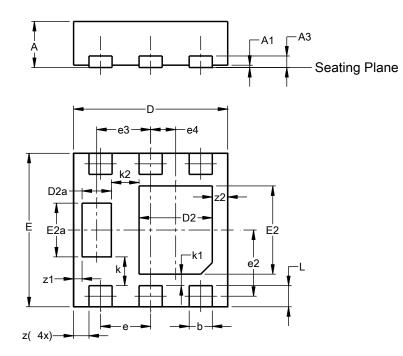




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

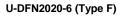


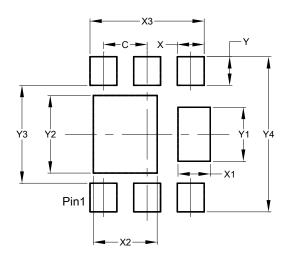


	U-DFN2020-6 (Type F)							
Dim	Min	Max	Typ					
A	0.57	0.63	Typ 0.60					
A1	0.00	0.05	0.03					
A3	-	-	0.15					
b	0.25	0.35	0.30					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
D2a	0.33	0.43	0.38					
E	1.95	2.05	2.00					
E2	1.05	1.25	1.15					
E2a	0.65	0.75	0.70					
е	0.65 BSC							
e2	0.863 BSC							
e3	0.70 BSC							
e4	0.325 BSC							
k	(0.37 BS	С					
k1	0.15 BSC							
k2	0.36 BSC							
L	0.225	0.325	0.275					
z		0.20 BS	С					
z1	C).110 BS	SC					
z2	1	0.20 BS	С					
All C	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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